
	<h2>SI1304BDL-T1-GE3</h2>
	<p>Hersteller-Teilenummer: SI1304BDL-T1-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 0.9A SC-70-3</p> <p>Datenblätter:  SI1304BDL-T1-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 118990 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1304BDL-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 30V 0.9A SC-70-3
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	118990 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SC-70, SOT-323
Supplier Device-Gehäuse	SC-70-3
Verlustleistung (max)	340mW (Ta), 370mW (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	900mA (Tc)
Rds On (Max) @ Id, Vgs	270 mOhm @ 900mA, 4.5V
VGS (th) (Max) @ Id	1.3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	2.7nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	100pF @ 15V
Verpackung	Tape & Reel (TR)



































SI1304BDL-T1-GE3 ist neu im Original, Suche SI1304BDL-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1304BDL-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1304BDL-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 SI1304DL-T1-E3 VISHAY SI1304DL-T1-E3 VISHAY	 SI1303EDL-T1-E3 Vishay / Siliconix MOSFET P-CH 20V 670MA SOT323-3	 SI1303EDL-T1-E3 Electro-Films (EFI) / Vishay MOSFET P-CH 20V 670MA SOT323-3	 SI1303EDL-T1-GE3 Vishay Precision Group SI1303EDL-T1-GE3 VISHAY
 SI1304DL VISHAY SI1304DL VISHAY	 SI1304DL-T1 VISHAY SI1304DL-T1 VISHAY	 SI1304BDL-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 0.9A SC-70-3	 SI1304BDL-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 0.9A SOT323-3

heiße Teile

Mehr

 SI1300BDL-T1-E3	 SI1300BDL-T1-GE3	 SI1300BDL-T1-GE3	D SI1300DL	 SI1300DL-T1
 SI1300DL-T1-GE3	 SI1301DL	D SI1301DL-T1	 SI1301DL-T1-E3	 SI1301DL-T1-GE3
 SI1301DL-T1/LGW	 SI1302DL	 SI1302DL-T1-E3	 SI1302DL-T1-E3	 SI1302DL-T1-GE3
D SI1302DL-T1-GE3	 SI1303DL	 SI1303DL-T1	 SI1303DL-T1-E3	 SI1303DL-T1-GE3
 SI1303DL-T1-GE3	 SI1303DL-T1-GE3	 SI1303DL-TL-E3	 SI1303EDL-T1-GE3	 SI1304BDL-T1-GE3
 SI1304DL	 SI1304DL-L	D SI1304DL-T1	 SI1304DL-T1-E3	 SI1304DL-T1-GE3
 SI1305DL	D SI1305DL-T1	 SI1305DL-T1-E3	 SI1305DL-T1-E3	 SI1305DL-T1-GE3
 SI1305DL-T1-GE3	 SI1305DL-T1-E3	 SI1305EDL	 SI1305EDL-T1-E3	 SI1305EDL-T1-GE3
 SI1305EDL-T1-GE3	 SI1305EDL-T1-GE3	 SI1305LT-T1-E3	D SI1306DL	 SI1307-DL-T1-E3
 SI1307DL	 SI1307DL-T1	 SI1307DL-T1-E3	 SI1307DL-T1-E3	 SI1307DL-T1-GE3

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